

Features

- Formerly FulTec brand
- Extremely high speed performance
- Blocks high voltages and currents
- Low insertion loss
- Two TBU[™] protectors in one small package
- Very high bandwidth; GHz compatible
- RoHS compliant*, UL Recognized Strength

TBU[™] P650-U and P850-U Protectors

Transient Blocking Units - TBU[™] Devices

Bourns[®] Model P650-U and P850-U TBU[™] products are high speed, unidirectional surge protection components designed to protect equipment against faults caused by AC power cross, induction and lightning surges.

The TBU[™] protector blocks surges and provides an effective barrier behind which sensitive electronics are not exposed to large voltages or currents during surge events.

Agency Approval

UL recognized component File # E315805.

Industry Standards

	Model		
Telcordia	GR-1089	Port Type 3, 5	P650-U
	GR-1089	Port Type 2, 4	P850-U
ITU-T	K.20, K.20E, K.21, K	P850-U	

Applications

Mb Ethernet port protection

Gb Ethernet port protection

Isolated and floating interfaces

Absolute Maximum Ratings (T_{amb} = 25 °C)

Symbol	Parameter	Value	Unit
V _{imp}	Maximum protection voltage for impulse faults with rise time \ge 1 µsec	650 850	V
V _{rms}	Maximum protection voltage for continuous V _{rms} faults connected as a series pair (refer to page 3 Test Configuration Diagram)	300 425	V
Т _{ор}	Operating temperature range	-40 to +85	°C
T _{stg}	Storage temperature range	-65 to +150	°C

Electrical Characteristics (T_{amb} = 25 °C)

Symbol	Parameter		Min.	Тур.	Max.	Unit	
		P650-U180-WH			180		
	Maximum current through the device that will not cause	P650-U260-WH			260	mA	
юр	current blocking	P850-U180-WH			180	mA	
		P850-U260-WH			260		
		P650-U180-WH		220			
Ι.	Typical current for the device to go from normal operating	P650-U260-WH		330		mΛ	
Itrigger	state to protected state	P850-U180-WH		220		mA	
		P850-U260-WH		330			
		P650-U180-WH			360		
	Maximum aurrent through the device	P650-U260-WH			520	mA	
lout	Maximum current through the device	P850-U180-WH			360		
		P850-U260-WH			520		
D	Series resistance of the TBU [™] device	P650-Uxxx-WH		6	7	Ω	
R _{TBU}	Series resistance of the TBO device	P850-Uxxx-WH		8	9	52	
R _{bal}	Line-to line series resistance difference between two TBU™	device			0.5	Ω	
+	Maximum time for the device to go from normal operating	P650-Uxxx-WH			1		
t _{block}	state to protected state			1	μs		
1	Current through the triggered TBU [™] device with 50 Vdc circu		1		mA		
Iquiescent	voltage			1		IIIA	
	Voltage below which the triggered TBU [™] device will	P650-Uxxx-WH		11			
V _{reset}	transition to normal operating state	P850-Uxxx-WH		14		V	

The P-U Series TBU[™] devices are unidirectional; specifications are valid for input direction only. For the output direction, the TBU[™] device is a resistor.

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Typical Performance Characteristics

V-I Characteristics



Time to Block vs. Fault Current



Trigger Current vs. Temperature



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Operational Characteristics

The graphs below demonstrate the operational characteristics of the TBU. For each graph the fault voltage, protected side voltage, and current is presented.

V1



P650-U Power Fault, 120 Vrms, 25 A



Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications



V2

Load

P850-U Power Fault, 230 Vrms, 25 A



Product Dimensions



Recommended Pad Layout



Pad Designation									
Pad #	Apply								
1	ln1								
2	NC								
3	Out1								
4	Out2								
5	NC								
6	In2								

6

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NC = Solder to PCB; do not make electrical connection, do not connect to ground.

TBU™ devices have matte-tin termination finish. Suggested layout should use non-solder mask define (NSMD). Recommended stencil thickness is 0.10-0.12 mm (.004-.005 in.) with stencil opening size 0.025 mm (.0010 in.) less than the device pad size. As when heat sinking any power device, it is recommended that, wherever possible, extra PCB copper area is allowed. For minimum parasitic capacitance, do not allow any signal, ground or power signals beneath any of the pads of the device.

Thermal Resistances

Symbol	Parameter	Value	Unit
Deres	Junction to leads (package)	105	°C/W
R _{th(j-a)}	Junction to leads (per TBU)	202	°C/W

Reflow Profile

Profile Feature	Pb-Free Assembly
Average Ramp-Up Rate (Tsmax to Tp)	3 °C/sec. max.
Preheat - Temperature Min. (Tsmin) - Temperature Max. (Tsmax) - Time (tsmin to tsmax)	150 °C 200 °C 60-180 sec.
Time maintained above: - Temperature (TL) - Time (tL)	217 °C 60-150 sec.
Peak/Classification Temperature (Tp) Time within 5 °C of Actual Peak Temp. (tp)	260 °C 20-40 sec.
Ramp-Down Rate Time 25 °C to Peak Temperature	6 °C/sec. max. 8 min. max.

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Dim.	Min.	Тур.	Max.
А	<u>6.15</u>	<u>6.25</u>	<u>6.35</u>
	(.242)	(.246)	(.250)
В	<u>7.65</u>	<u>7.75</u>	7.85
	(.301)	(.305)	(.309)
С	<u>0.80</u>	<u>0.85</u>	<u>0.90</u>
	(.031)	(.033)	(.035)
D	<u>0.000</u>	0.025	0.050
	(.000)	(.001)	(.002)
E	<u>0.50</u> (.020)	<u>0.55</u> (.022)	$\frac{0.60}{(.024)}$
F	<u>1.20</u>	<u>1.25</u>	<u>1.30</u>
	(.047)	(.049)	(.051)
G	<u>4.20</u>	<u>4.25</u>	<u>4.30</u>
	(.165)	(.167)	(.169)
Н	<u>2.45</u>	<u>2.50</u>	<u>2.55</u>
	(.096)	(.098)	(.100)
J	<u>0.20</u>	<u>0.25</u>	<u>0.30</u>
	(.008)	(.010)	(.012)
К	<u>0.45</u>	<u>0.50</u>	<u>0.55</u>
	(.018)	(.020)	(.022)
L	<u>0.65</u>	<u>0.70</u>	<u>0.75</u>
	(.026)	(.028)	(.030)
Ν	<u>0.20</u>	<u>0.25</u>	<u>0.30</u>
	(.008)	(.010)	(.012)
Р	<u>0.70</u>	<u>0.75</u>	<u>0.80</u>
	(.028)	(.030)	(.031)
Q	<u>3.20</u>	<u>3.25</u>	<u>3.30</u>
	(.126)	(.128)	(.130)

MM DIMENSIONS: (INCHES)

Block Diagram





Specifications are subject to change without notice. Customers should verify actual device performance in their specific applications

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Device	A		В		С		D		G	N
Device	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Ref.	Ref.
P650-U, P850-U	<u>326</u> (12.835)	<u>330.25</u> (13.002)	<u>1.5</u> (.059)	<u>2.5</u> (.098)	<u>12.8</u> (.504)	<u>13.5</u> (.531)	<u>20.2</u> (.795)	-	<u>16.5</u> (.650)	<u>102</u> (4.016)

Device	A ₀		B ₀		D		D ₁		E		F	
Device	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	max.
P650-U, P850-U	<u>6.5</u> (.256)	<u>6.7</u> (.264)	<u>8.0</u> (.315)	<u>8.2</u> (.323)	<u>1.5</u> (.059)	<u>1.6</u> (.063)	<u>1.5</u> (.059)	-	<u>1.65</u> (.065)	<u>1.85</u> (.073)	<u>7.4</u> (.291)	<u>7.6</u> (.299)
Device	K0		Р		P0		P2		t		W	
Device	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
P650-U, P850-U	<u>1.4</u> (.055)	<u>1.6</u> (.063)	<u>11.9</u> (.469)	<u>12.1</u> (.476)	<u>3.9</u> (.159)	<u>4.1</u> (.161)	<u>1.9</u> (.075)	<u>2.1</u> (.083)	<u>0.25</u> (.010)	<u>0.35</u> (.014)	<u>15.7</u> (.618)	<u>16.3</u> (.642)

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Reference Applications

A cost-effective protection solution utilizes the Bourns[®] TBU[™] protection devices. The diagrams below illustrate common configurations of these components. The graph at the bottom demonstrates the operational characteristics of the circuit.



GbE Ethernet Protection Up to 1500 V Lightning Protection



P850-U with G5200AS 4000 V Lightning 10/700 µsec, 150 A



GbE Ethernet Protection Up to 6000 V Lightning Protection



Asia-Pacific: Tel: +886-2 2562-4117 • Fax: +886-2 2562-4116 Europe: Tel: +41-41 768 5555 • Fax: +41-41 768 5510

The Americas: Tel: +1-951 781-5500 • Fax: +1-951 781-5700

www.bourns.com